

## TRANSMITTAL

Electronic Version v1.1

Stylesheet Version v1.1.0

<b>Title of Invention</b>	Method of Forming Thin Silicon Oxide Films on Silicon Carbide Substrates	
<p>Application Number :</p> <p>Date :</p> <p>First Named Applicant: Andrew M. Hoff</p> <p>Confirmation Number:</p> <p>Attorney Docket Number: 1372,80.PRC</p>		
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<b>Documents being submitted:</b>	<b>Files</b>
us-request	1372_80_PRC-usrequ.xml us-request.dtd us-request.xsl
us-declaration	1372_80_PRC-usdecl.xml us-declaration.dtd us-declaration.xsl
us-fee-sheet	1372_80_PRC-usfees.xml us-fee-sheet.xsl us-fee-sheet.dtd
us-power-of-attorney-grant	1372_80_PRC-uspoat.xml us-power-of-attorney-grant.dtd us-power-of-attorney-grant.xsl
application-body	Specification-trans.xml us-application-body.xsl application-body.dtd wipo.ent mathml2.dtd mathml2-qname-1.mod isoamsa.ent isoamsb.ent isoamsc.ent isoamsn.ent isoamso.ent isoamsr.ent isogrk3.ent isomfrk.ent isomopf.ent isomscr.ent isotech.ent isobox.ent isocyr1.ent isocyr2.ent isodia.ent isolat1.ent isolat2.ent isonum.ent isopub.ent mmlextra.ent mmlalias.ent soextblk.dtd FIG0102_1.TIF
<b>Comments</b>	